LAYERED PRESSURE SENSITIVE TRANSDUCER AND METHOD FOR MAKING SAME

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<u>US4996511; US4933660; US4492949; US4495236; US4315238; JP59135581; JP53145655</u>

Abstract

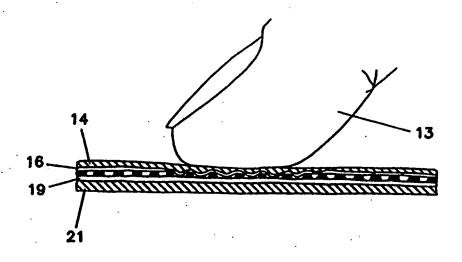
A variable resistance transducer responsive to an applied pressure is disclosed comprising a smooth resistive layer on a flexible substrate and deposited thereon by printing or imaging technology, small points of nonconductive or semiconductive material.

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(54) Title: LAYERED PRESSURE SENSITIVE TRANSDUCER AND METHOD FOR MAKING SAME



(57) Abstract

A variable resistance transducer responsive to an applied pressure is disclosed comprising a smooth resistive layer on a flexible substrate and deposited thereon by printing or imaging technology, small points of nonconductive or semiconductive material.